

NE3513M04

Data Sheet R09DS0028EJ0100 Rev.1.00 Oct 18, 2011

N-Channel GaAs HJ-FET, X to Ku Band Low Noise and High-Gain

FEATURES

- Low noise figure and high associated gain:
 - NF = 0.45 dB TYP., $G_a = 13$ dB TYP. $@V_{DS} = 2 V$, $I_D = 10 mA$, f = 12 GHzNF = 0.5 dB TYP., $G_a = 12 dB TYP$. $@V_{DS} = 2 V$, $I_D = 6 mA$, f = 12 GHz (Reference Value)
- Flat-lead 4-pin thin-type super minimold (M04) package

APPLICATIONS

- DBS LNB gain-stage, Mix-stage
- Low noise amplifier for microwave communication system

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Marking	Supplying Form
NE3513M04-T2	NE3513M04-T2-A	Flat-lead 4-pin thin-type super	3 kpcs/reel	V84	 Embossed tape 8 mm wide Pin 1 (Source), Pin 2 (Drain)
NE3513M04-T2B	NE3513M04-T2B-A	_ minimold (M04) (Pb-Free)	15 kpcs/reel		face the perforation side of the tape

Remark To order evaluation samples, please contact your nearby sales office. Part number for sample order: NE3513M04-A

ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Parameter	Symbol	Ratings	Unit
Drain to Source Voltage	V _{DS}	4.0	V
Gate to Source Voltage	V _{GS}	-3.0	V
Drain Current	Ι _D	I _{DSS}	mA
Gate Current	l _G	80	μA
Total Power Dissipation Note	P _{tot}	125	mW
Channel Temperature	T _{ch}	+125	°C
Storage Temperature	T _{stg}	–65 to +125	°C

Note: Mounted on 1.08 $\text{cm}^2 \times 1.0 \text{ mm}$ (t) glass epoxy PWB

CAUTION

Observe precautions when handling because these devices are sensitive to electrostatic discharge.



RECOMMENDED OPERATING RANGE ($T_A = +25^{\circ}C$, unless otherwise specified)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Drain to Source Voltage	V _{DS}	+1	+2	+3	V
Drain Current	I _D	3	10	15	mA
Input Power	Pin	-	_	0	dBm

ELECTRICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)

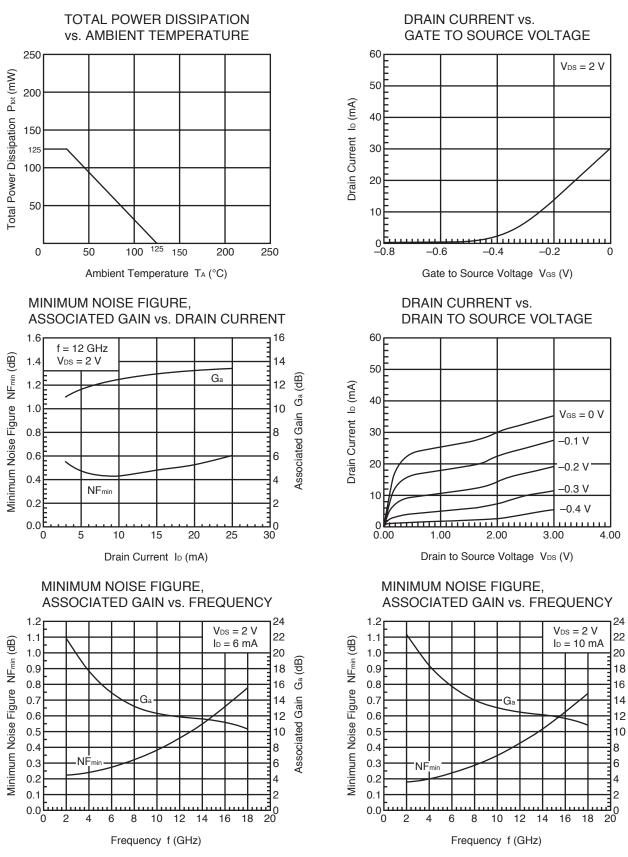
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	I _{GSO}	$V_{GS} = -3.0 V$	-	0.5	10	μA
Saturated Drain Current	I _{DSS}	$V_{DS} = 2 V, V_{GS} = 0 V$	15	30	60	mA
Gate to Source Cut-off Voltage	V _{GS (off)}	$V_{DS} = 2 \text{ V}, \text{ I}_{D} = 100 \ \mu\text{A}$	-0.2	-0.5	-1.3	V
Transconductance	gm	$V_{DS} = 2 V, I_D = 10 mA$	50	65	-	mS
Noise Figure	NF	V _{DS} = 2 V, I _D = 10 mA, f = 12 GHz	_	0.45	0.65	dB
Associated Gain	Ga		11.5	13	_	dB

STANDARD CHARACTERISTICS FOR REFERENCE $(T_A = +25^{\circ}C, unless otherwise specified)$

Parameter	Symbol	Test Conditions	Reference Value	Unit
Noise Figure	NF	V_{DS} = 2 V, I_{D} = 6 mA, f = 12 GHz	0.5	dB
Associated Gain	Ga		12	dB



TYPICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)





(qB)

g

Associated Gain

S-PARAMETERS

S-parameters/Noise-parameters are provided on our web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.

Click here to download S-parameters.

[RF and Microwave] [Device Parameters]

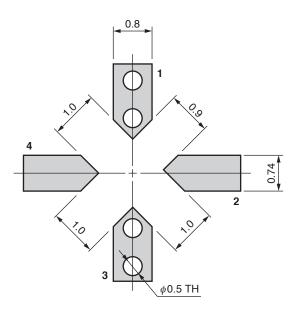
URL http://www2.renesas.com/microwave/



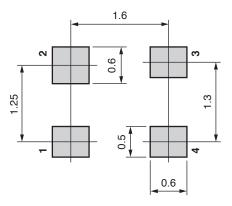
MOUNTING PAD DIMENSIONS

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) (UNIT: mm)

-Reference 1-



-Reference 2-



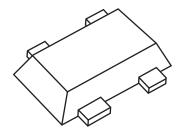
Remark The mounting pad layout in this document is for reference only.

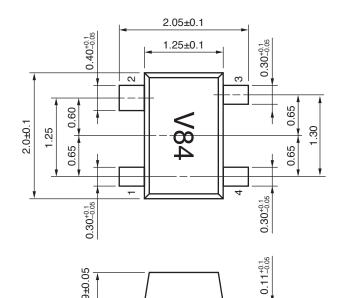


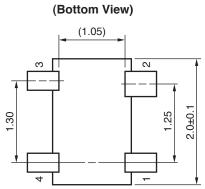
PACKAGE DIMENSIONS

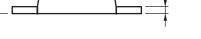
0.59±0.05

FLAT-LEAD 4-PIN THIN-TYPE SUPER MINIMOLD (M04) (UNIT: mm)









PIN CONNECTIONS

- 1. Source
- 2. Drain
- 3. Source
- 4. Gate



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol	
Infrared Reflow	Peak temperature (package surface temperature) : 260°C or below		IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher : 60 seconds or less		
	Preheating time at 120 to 180°C : 120±30 seconds		
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2% (Wt.) or below	
Partial Heating	Peak temperature (terminal temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2% (Wt.) or below	

CAUTION

Do not use different soldering methods together (except for partial heating).





Caution GaAs Products	This product uses gallium arsenide (GaAs). GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
	 Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
	 Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
	Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
	• Do not burn, destroy, cut, crush, or chemically dissolve the product.
	 Do not lick the product or in any way allow it to enter the mouth.



NE3513M04 Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Oct 18, 2011	-	First edition issued	